

Disorder in $\text{La}_{1-x}\text{Ba}_{1+x}\text{GaO}_{4-x/2}$ ionic conductor: resolving Pair Distribution Function through insight from first principles modelling

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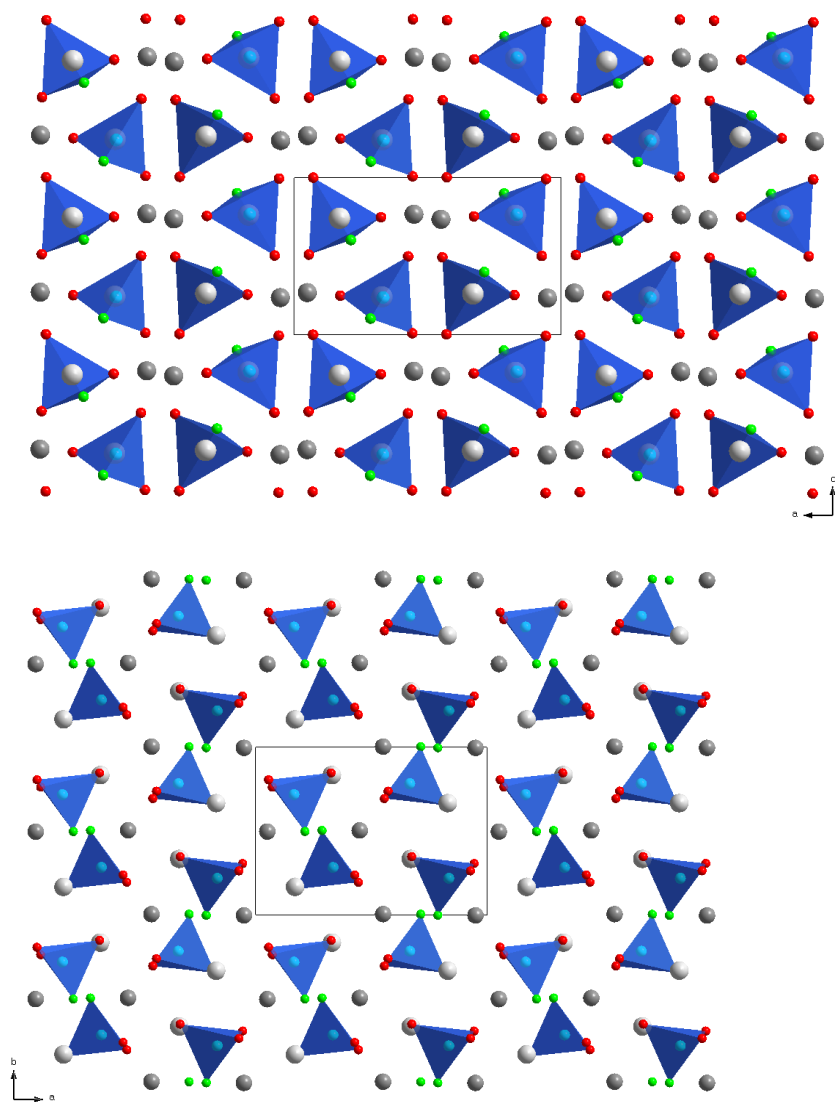


Figure S11. View of tetrahedral connectivity in LaBaGaO₄ along *b* (top) and *c* axis (bottom).

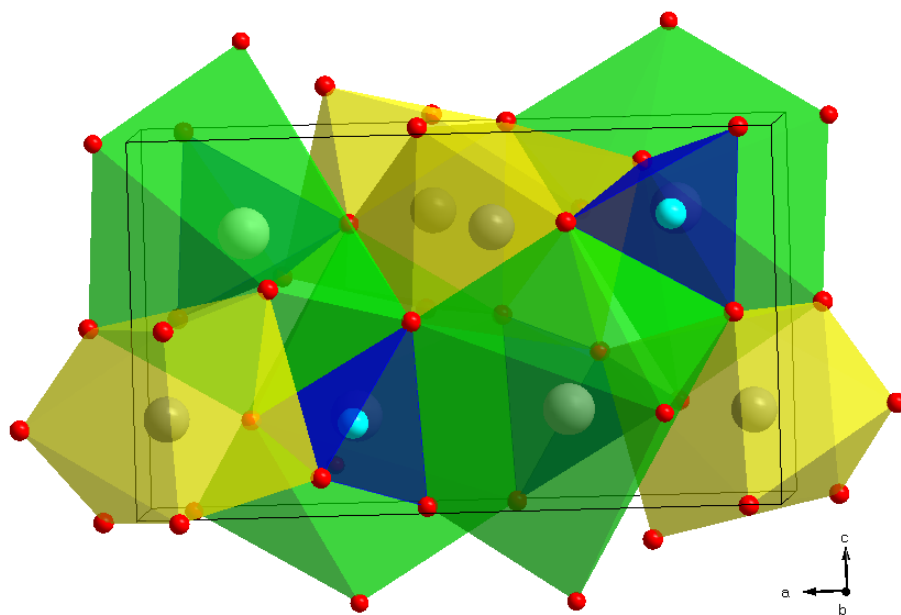


Figure SI2. Unit cell of LaBaGaO₄ highlighting the polyhedra characteristic of Ga (blue), Ba (green) and La (yellow).

Table S11. Interatomic distances of interest (Å) from DFT.

| | LaBaGaO4 | model 1 | model 2 | model 3 | model 4 |
|------------------------------------|----------|---------|---------|---------|---------|
| Ga _A - O br | - | 2.114 | 2.071 | 2.036 | 1.994 |
| Ga _A - O | 1.846 | 1.765 | 1.809 | 1.806 | 1.771 |
| | 1.864 | 1.852 | 1.755 | 1.870 | 1.882 |
| | 1.842 | 1.821 | 1.805 | 1.786 | 1.794 |
| | 1.838 | - | - | - | - |
| Ga _B - O br | - | 2.063 | 1.973 | 2.040 | 2.050 |
| Ga _B - O | 1.846 | 1.818 | 1.856 | 1.848 | 1.838 |
| | 1.864 | 1.815 | 1.793 | 1.765 | 1.768 |
| | 1.842 | 1.736 | 1.868 | 1.743 | 1.775 |
| | 1.838 | - | - | - | - |
| NN Ba-O br | 2.562* | 2.700 | 2.728 | 2.815 | 2.626 |
| | 3.479* | 2.756 | 2.773 | 3.236 | 3.326 |
| | - | 3.010 | 3.123 | - | - |
| NN La-O br | 2.549* | 2.604 | 2.547 | 2.489 | 2.653 |
| | 2.587* | - | - | 2.723 | 2.724 |
| Ba' _{La} - O br | - | 2.756 | 2.728 | 4.623 | 5.275 |
| | - | 4.797 | 6.737 | 5.092 | 5.586 |
| | - | 5.097 | 7.090 | 5.115 | 6.199 |
| | - | 7.752 | 7.611 | 7.594 | 7.297 |
| | - | 7.851 | 7.865 | 7.693 | 8.870 |
| Ba' _{La} - V _O | - | 4.421 | 2.350 | 4.726 | 2.791 |
| | - | 5.022 | 4.876 | 6.424 | 7.152 |
| NN cation - cation | 3.707 | 3.589 | 3.588 | 3.808 | 3.658 |
| | 3.707 | 3.840 | 3.851 | 3.852 | 3.810 |
| | 3.899 | 4.091 | 4.061 | 4.099 | 4.191 |
| | 4.908 | 4.106 | 4.203 | 4.118 | 4.221 |

* NN O ion is considered rather than O bridge.

Table SI2. Ga-O bond angles (deg.) from DFT.

| | LaBaGaO ₄ | model 1 | model 2 | model 3 | model 4 |
|------------------------|----------------------|---------|---------|---------|---------|
| Ga _A - O br | 97.99* | 91.46 | 94.25 | 98.24 | 96.58 |
| | 103.41* | 101.45 | 106.51 | 102.97 | 103.00 |
| | 104.31* | 135.56 | 121.21 | 107.79 | 122.51 |
| Ga _A - O | 108.81 | 103.04 | 108.25 | 112.42 | 108.59 |
| | 111.26 | 107.28 | 111.02 | 115.52 | 112.16 |
| | 130.13 | 118.86 | 113.17 | 117.36 | 113.19 |
| Ga _B - O br | - | 102.58 | 100.25 | 93.35 | 95.51 |
| | - | 103.06 | 102.59 | 100.04 | 101.55 |
| | - | 112.52 | 131.68 | 140.30 | 129.55 |
| Ga _B - O | - | 111.52 | 109.93 | 100.64 | 102.73 |
| | - | 111.87 | 110.54 | 105.60 | 110.97 |
| | - | 114.35 | 100.96 | 118.01 | 116.49 |

* NN O ion is considered rather than O bridge.